Date/Time: 4/7/2011 3:43:32 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 824.2 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

GSM850_open/L ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

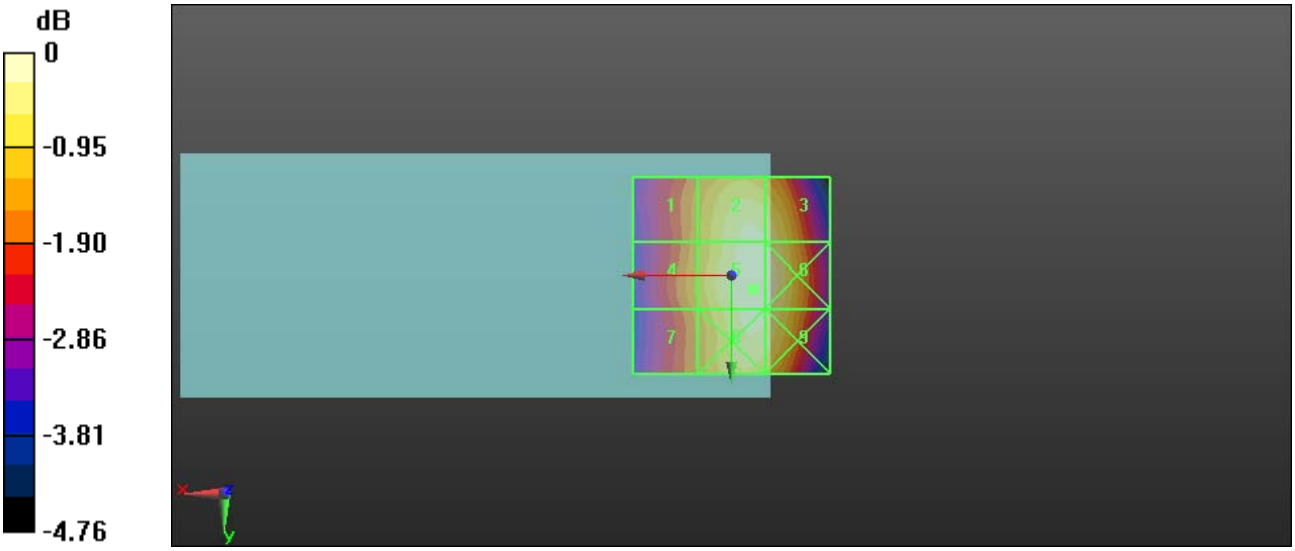
Maximum value of peak Total field = 176.1 V/m
Probe Modulation Factor = 2.790
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 79.356 V/m; Power Drift = -0.04 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **151.2 M3**	Grid 2 **172.5 M3**	Grid 3 **171.0 M3**
Grid 4 **154.2 M3**	Grid 5 **176.1 M3**	Grid 6 **175.2 M3**
Grid 7 **150.5 M3**	Grid 8 **173.6 M3**	Grid 9 **172.0 M3**

Cursor:
Total = 176.1 V/m
E Category: M3
Location: -5.5, 3.5, 8.7 mm



0 dB = 176.1V/m

Date/Time: 4/7/2011 3:36:58 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 836.6 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

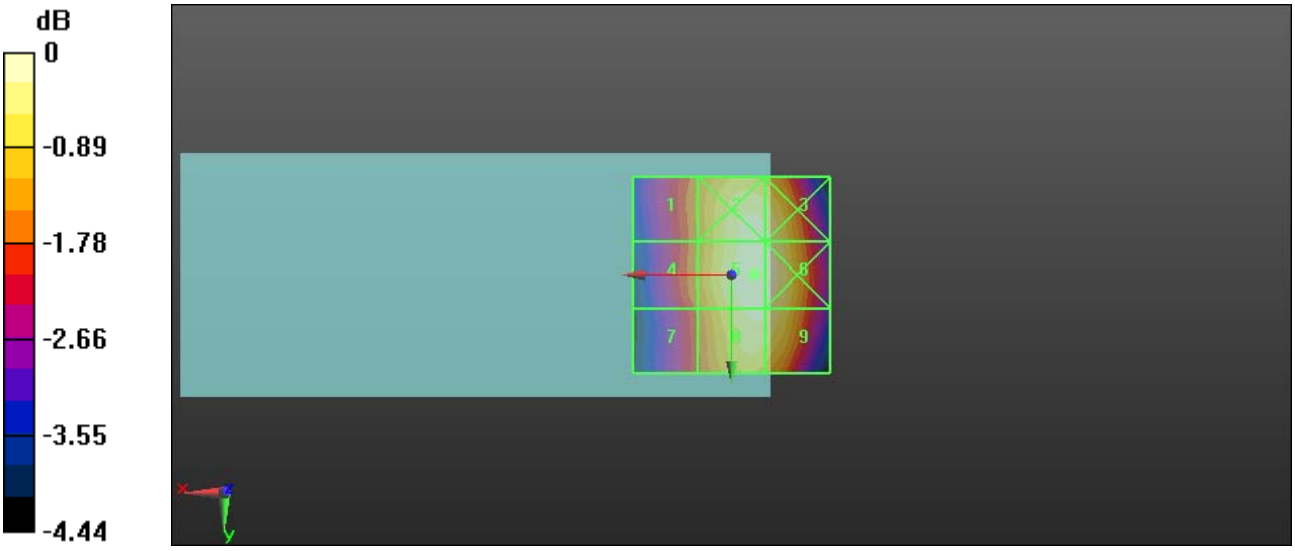
GSM850_open/M ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 161.9 V/m
Probe Modulation Factor = 2.790
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 72.260 V/m; Power Drift = -0.04 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **138.0 M4**	Grid 2 **159.8 M3**	Grid 3 **158.9 M3**
Grid 4 **138.2 M4**	Grid 5 **161.9 M3**	Grid 6 **160.9 M3**
Grid 7 **134.2 M4**	Grid 8 **158.8 M3**	Grid 9 **157.8 M3**

Cursor:
Total = 161.9 V/m
E Category: M3
Location: -6, 0, 8.7 mm



0 dB = 161.9V/m

Date/Time: 4/7/2011 3:51:58 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 848.8 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

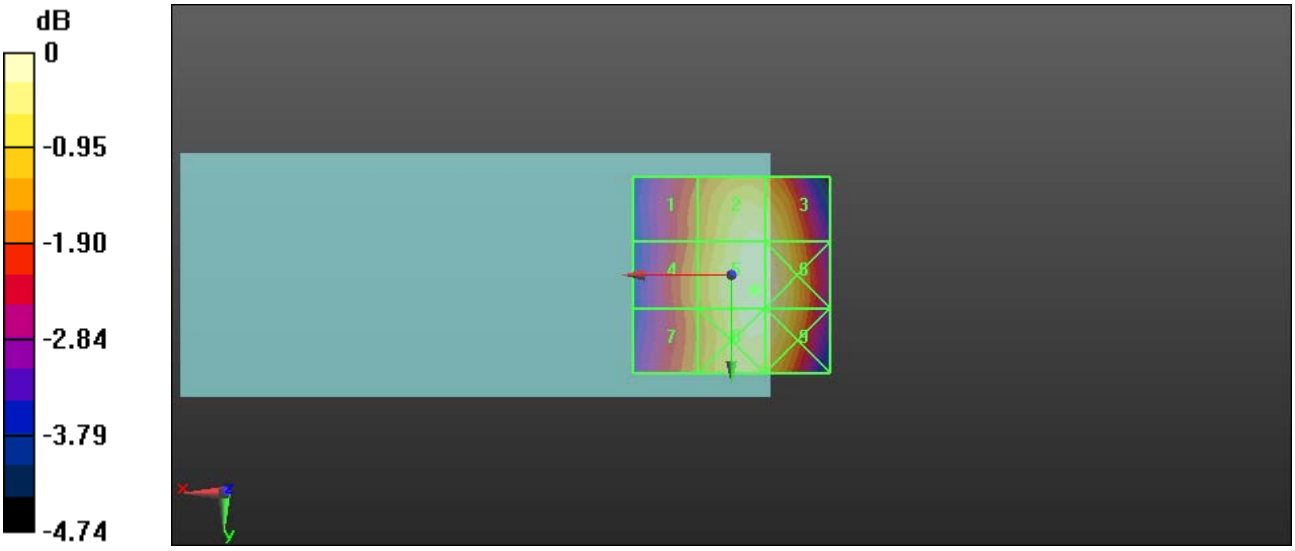
GSM850_open/H ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 139.5 V/m
Probe Modulation Factor = 2.790
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 62.213 V/m; Power Drift = -0.03 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **117.2 M4**	Grid 2 **135.8 M4**	Grid 3 **135.0 M4**
Grid 4 **120.4 M4**	Grid 5 **139.5 M4**	Grid 6 **138.9 M4**
Grid 7 **118.9 M4**	Grid 8 **137.8 M4**	Grid 9 **136.9 M4**

Cursor:
Total = 139.5 V/m
E Category: M4
Location: -6, 4, 8.7 mm



0 dB = 139.5V/m

Date/Time: 4/7/2011 11:49:56 AM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 824.2 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

GSM850_closed/L ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

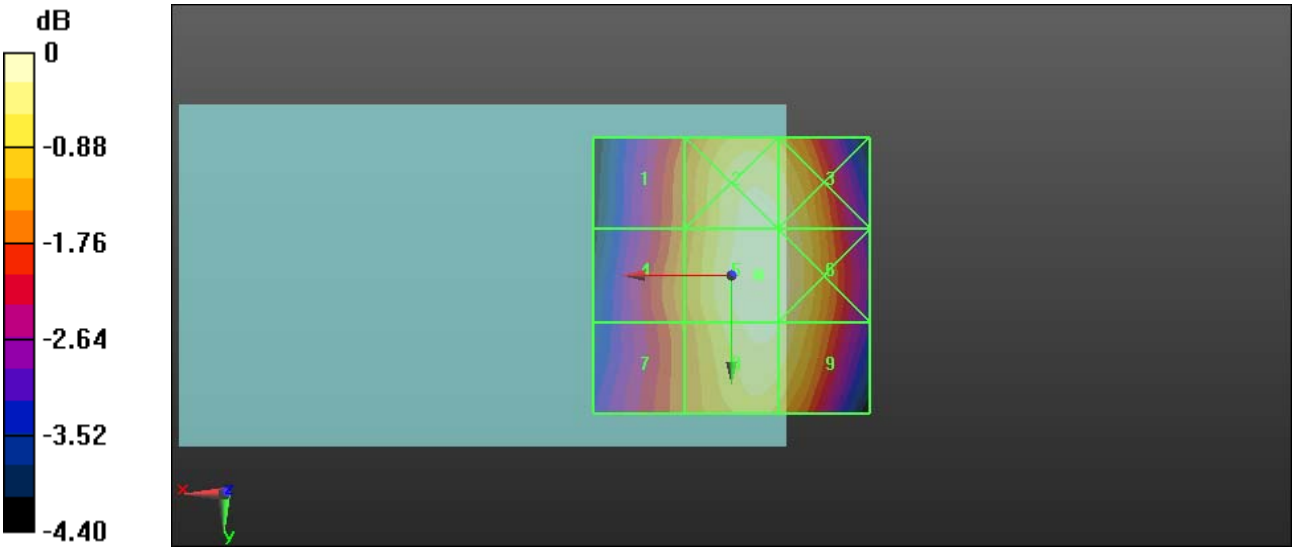
Maximum value of peak Total field = 165.4 V/m
Probe Modulation Factor = 2.790
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 73.371 V/m; Power Drift = 0.12 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **140.8 M4**	Grid 2 **163.0 M3**	Grid 3 **161.2 M3**
Grid 4 **143.8 M4**	Grid 5 **165.4 M3**	Grid 6 **163.7 M3**
Grid 7 **141.4 M4**	Grid 8 **162.4 M3**	Grid 9 **160.6 M3**

Cursor:
Total = 165.4 V/m
E Category: M3
Location: -5, 0, 8.7 mm



0 dB = 165.4V/m

Date/Time: 4/7/2011 11:43:01 AM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 836.6 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

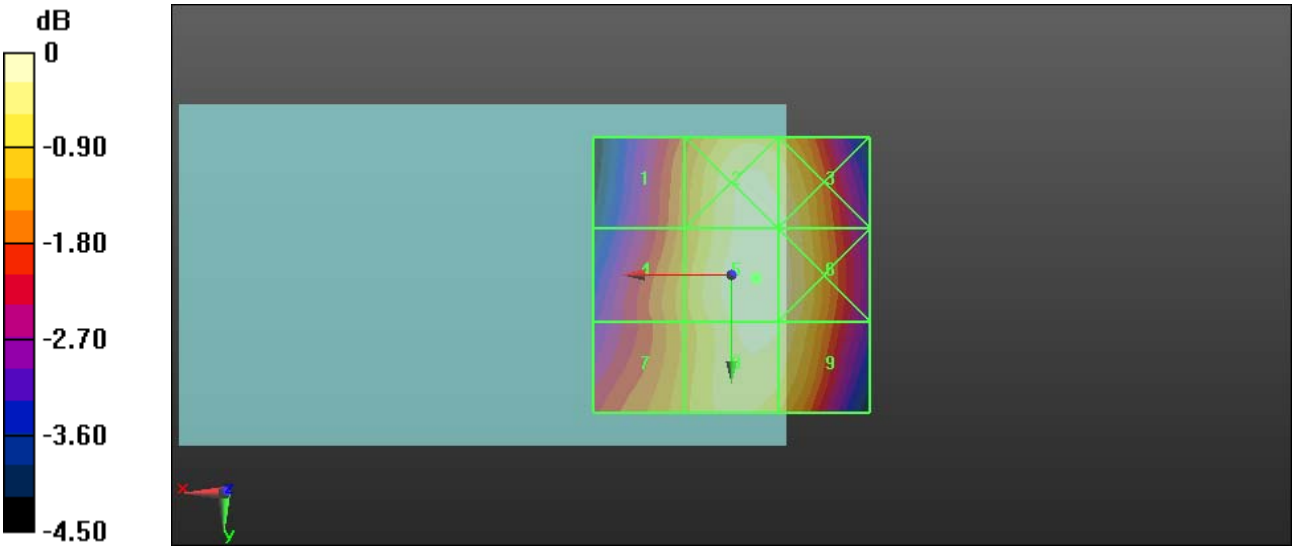
GSM850_closed/M ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 151.7 V/m
Probe Modulation Factor = 2.790
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 68.349 V/m; Power Drift = -0.04 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **130.7 M4**	Grid 2 **149.8 M3**	Grid 3 **148.4 M4**
Grid 4 **135.6 M4**	Grid 5 **151.7 M3**	Grid 6 **150.2 M3**
Grid 7 **135.6 M4**	Grid 8 **149.1 M4**	Grid 9 **147.4 M4**

Cursor:
Total = 151.7 V/m
E Category: M3
Location: -4.5, 0.5, 8.7 mm



0 dB = 151.7V/m

Date/Time: 4/7/2011 11:56:11 AM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 848.8 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

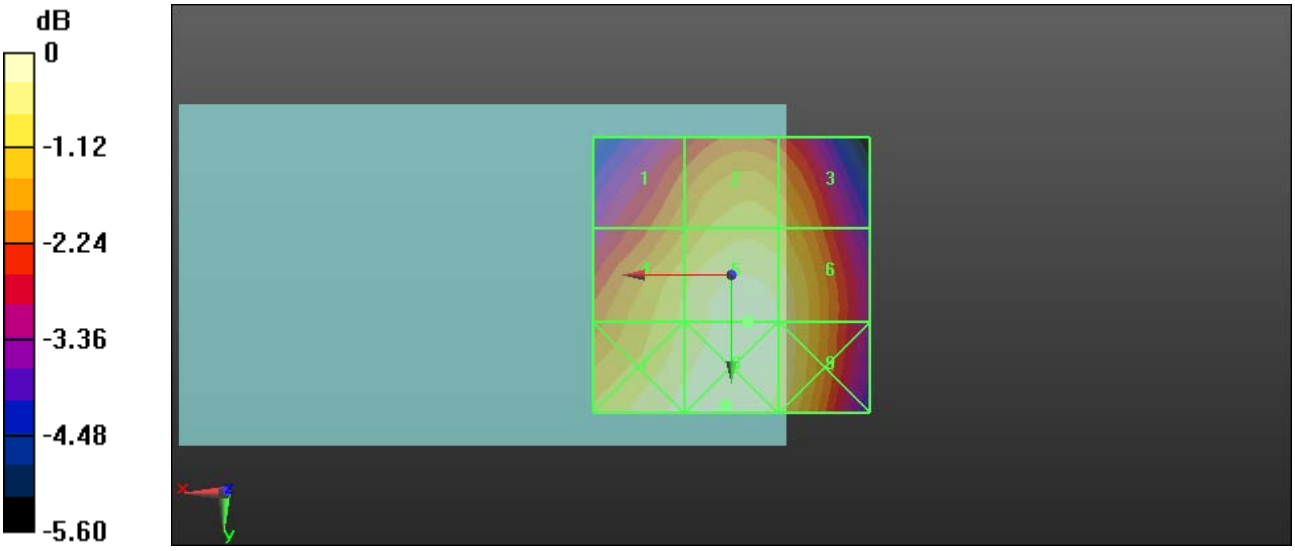
GSM850_closed/H ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 145.7 V/m
Probe Modulation Factor = 2.790
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 64.238 V/m; Power Drift = -0.03 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **125.1 M4**	Grid 2 **134.8 M4**	Grid 3 **132.1 M4**
Grid 4 **137.9 M4**	Grid 5 **145.7 M4**	Grid 6 **142.3 M4**
Grid 7 **145.1 M4**	Grid 8 **148.8 M4**	Grid 9 **142.8 M4**

Cursor:
Total = 148.8 V/m
E Category: M4
Location: 1, 23.5, 8.7 mm



0 dB = 148.8V/m

Date/Time: 4/7/2011 3:12:39 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1850.2 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

GSM1900_open/L ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

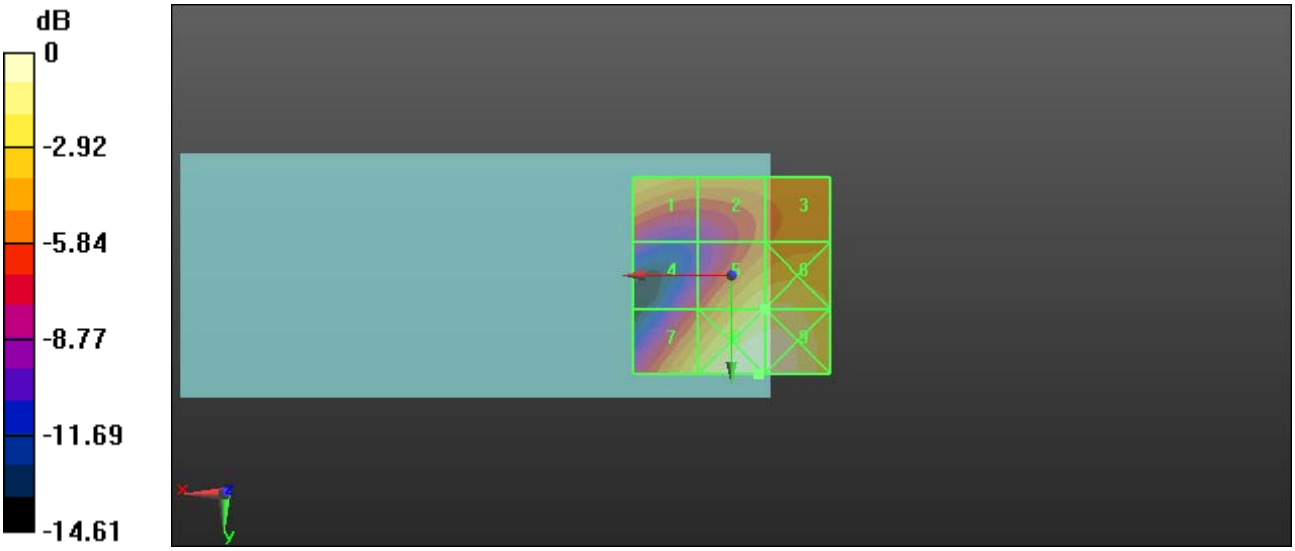
Maximum value of peak Total field = 61.070 V/m
Probe Modulation Factor = 2.820
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 16.009 V/m; Power Drift = 0.17 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **55.432 M3**	Grid 2 **47.072 M4**	Grid 3 **47.882 M3**
Grid 4 **35.944 M4**	Grid 5 **61.070 M3**	Grid 6 **62.258 M3**
Grid 7 **58.085 M3**	Grid 8 **75.418 M3**	Grid 9 **75.138 M3**

Cursor:
Total = 75.418 V/m
E Category: M3
Location: -7, 25, 8.7 mm



0 dB = 75.420V/m

Date/Time: 4/7/2011 3:06:18 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1880 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

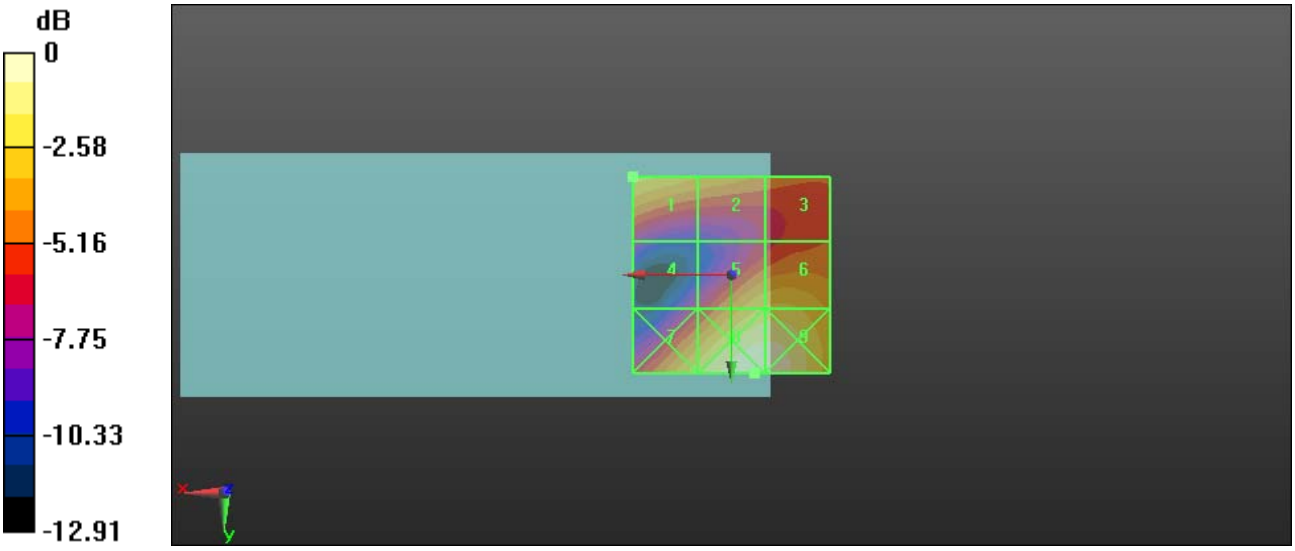
GSM1900_open/M ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 60.429 V/m
Probe Modulation Factor = 2.820
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 14.163 V/m; Power Drift = -0.03 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **60.429 M3**	Grid 2 **53.134 M3**	Grid 3 **46.506 M4**
Grid 4 **35.813 M4**	Grid 5 **58.664 M3**	Grid 6 **59.806 M3**
Grid 7 **62.236 M3**	Grid 8 **77.817 M3**	Grid 9 **77.233 M3**

Cursor:
Total = 77.817 V/m
E Category: M3
Location: -6, 25, 8.7 mm



0 dB = 77.820V/m

Date/Time: 4/7/2011 3:22:57 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1909.8 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

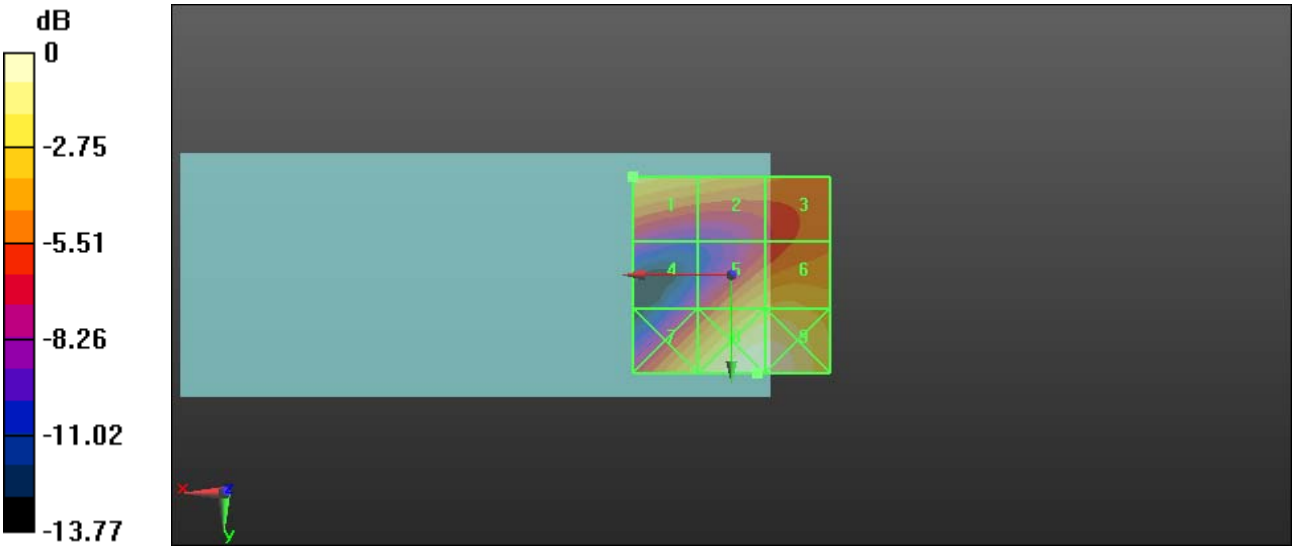
GSM1900_open/H ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 58.544 V/m
Probe Modulation Factor = 2.820
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 12.455 V/m; Power Drift = 0.02 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **58.544 M3**	Grid 2 **52.498 M3**	Grid 3 **46.493 M4**
Grid 4 **32.824 M4**	Grid 5 **56.121 M3**	Grid 6 **57.851 M3**
Grid 7 **59.738 M3**	Grid 8 **75.840 M3**	Grid 9 **75.417 M3**

Cursor:
Total = 75.840 V/m
E Category: M3
Location: -6.5, 25, 8.7 mm



0 dB = 75.840V/m

Date/Time: 4/7/2011 12:11:40 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1850.2 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

GSM1900_closed/L ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

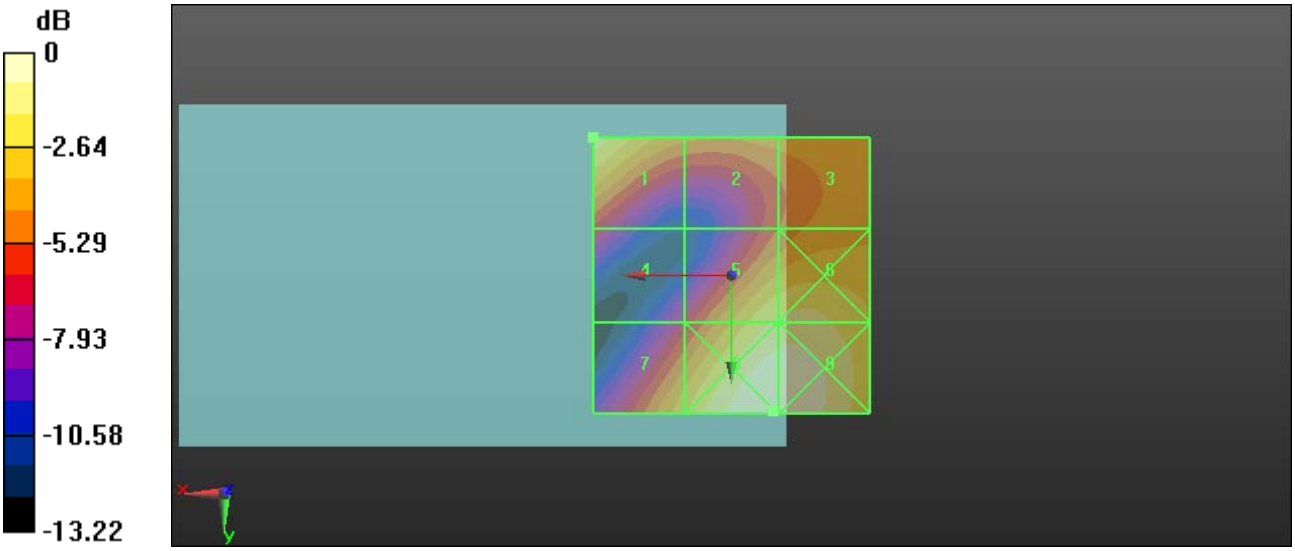
Maximum value of peak Total field = 58.641 V/m
Probe Modulation Factor = 2.820
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 14.043 V/m; Power Drift = 0.05 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **58.641 M3**	Grid 2 **42.677 M4**	Grid 3 **43.813 M4**
Grid 4 **32.597 M4**	Grid 5 **55.785 M3**	Grid 6 **57.178 M3**
Grid 7 **48.987 M3**	Grid 8 **67.085 M3**	Grid 9 **67.019 M3**

Cursor:
Total = 67.085 V/m
E Category: M3
Location: -7.5, 24.5, 8.7 mm



0 dB = 67.090V/m

Date/Time: 4/7/2011 12:05:14 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1880 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

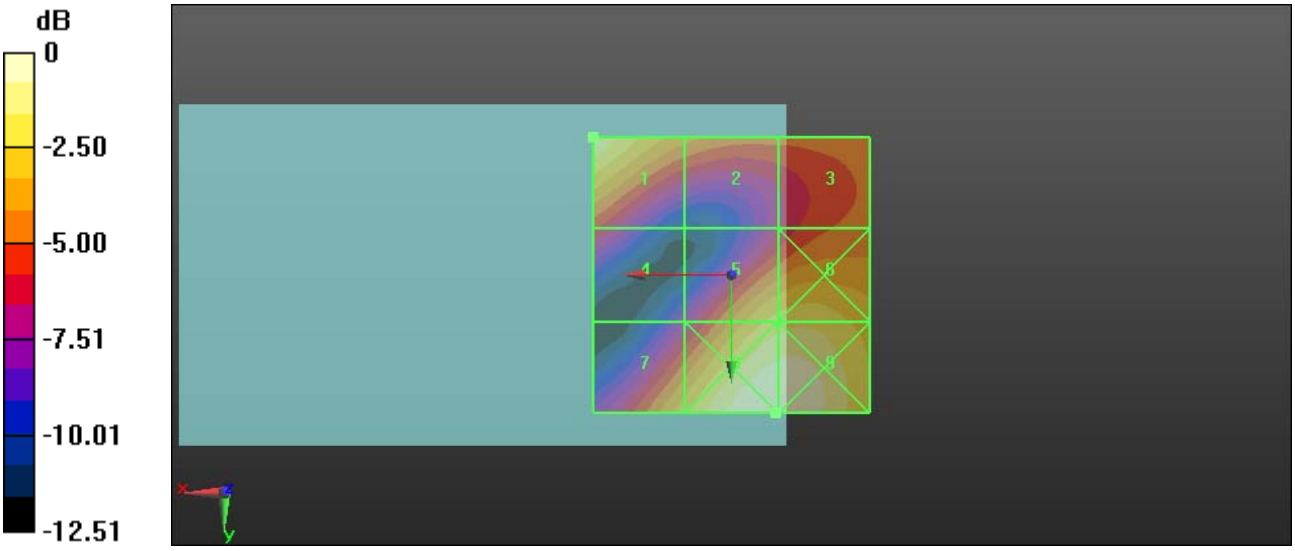
GSM1900_closed/M ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 64.221 V/m
Probe Modulation Factor = 2.820
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 12.656 V/m; Power Drift = 0.03 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **64.221 M3**	Grid 2 **46.075 M4**	Grid 3 **42.022 M4**
Grid 4 **37.094 M4**	Grid 5 **55.745 M3**	Grid 6 **57.524 M3**
Grid 7 **51.905 M3**	Grid 8 **71.144 M3**	Grid 9 **71.111 M3**

Cursor:
Total = 71.143 V/m
E Category: M3
Location: -8, 25, 8.7 mm



0 dB = 71.140V/m

Date/Time: 4/7/2011 12:17:53 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1909.8 MHz;Duty Cycle: 1:8.00018
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

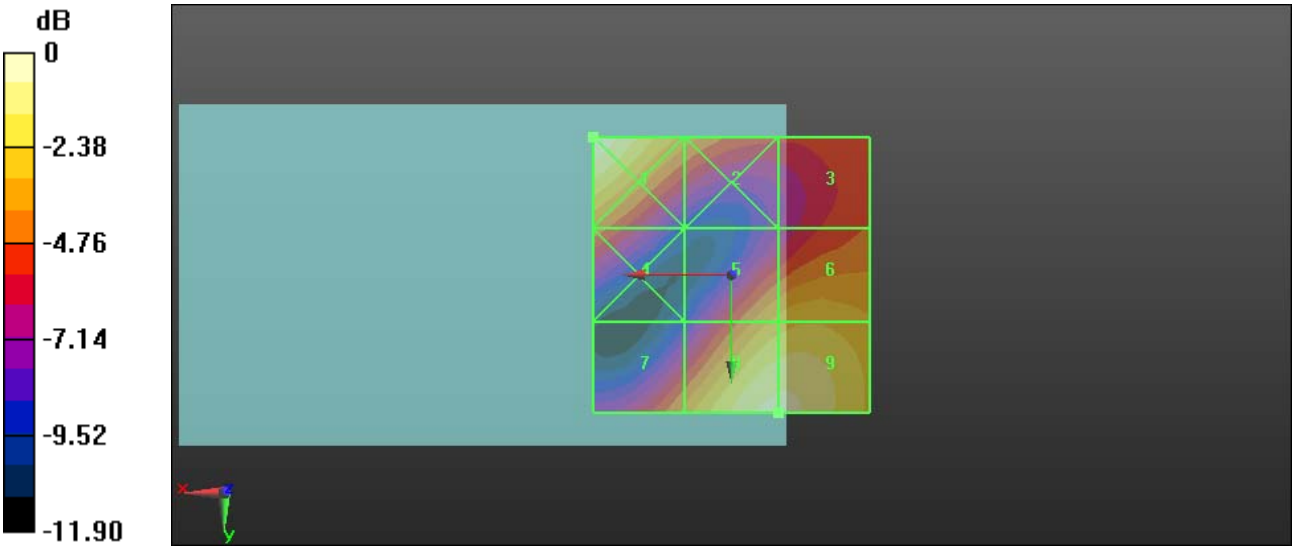
GSM1900_closed/H ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 60.521 V/m
Probe Modulation Factor = 2.820
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 9.562 V/m; Power Drift = -0.13 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **64.872 M3**	Grid 2 **43.511 M4**	Grid 3 **37.824 M4**
Grid 4 **40.171 M4**	Grid 5 **46.605 M4**	Grid 6 **49.051 M3**
Grid 7 **42.781 M4**	Grid 8 **60.521 M3**	Grid 9 **60.521 M3**

Cursor:
Total = 64.872 V/m
E Category: M3
Location: 25, -25, 8.7 mm



0 dB = 64.870V/m

Date/Time: 4/7/2011 2:19:55 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 824.7 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

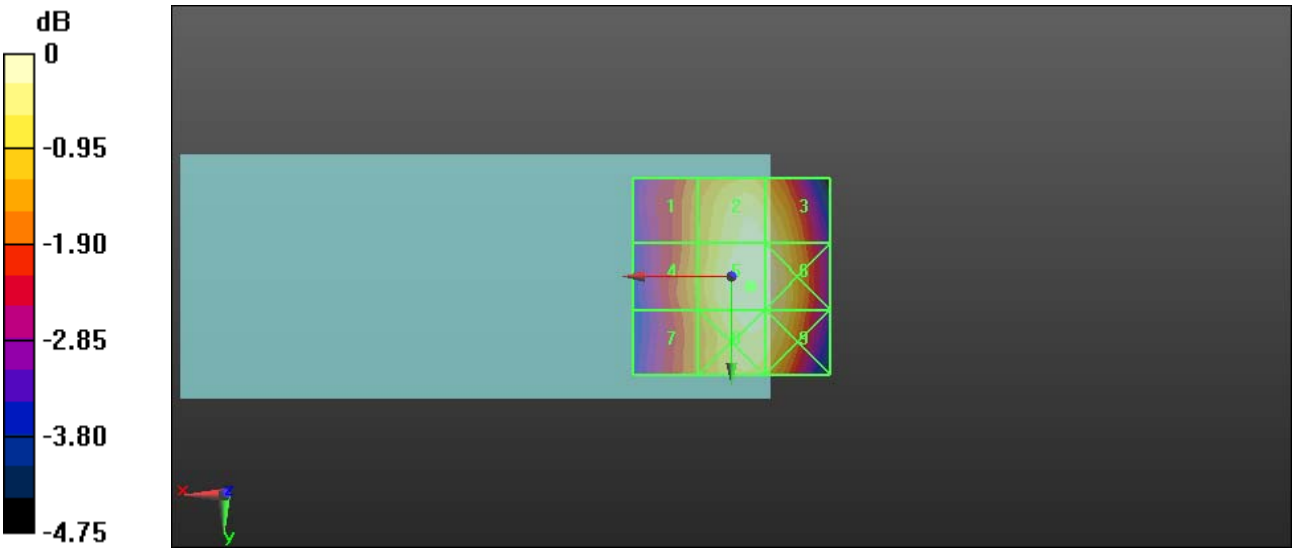
CDMA2000 Cell band_open/L ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 56.093 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 74.420 V/m; Power Drift = -0.0022 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **48.369 M4**	Grid 2 **54.961 M4**	Grid 3 **54.498 M4**
Grid 4 **49.229 M4**	Grid 5 **56.093 M4**	Grid 6 **55.690 M4**
Grid 7 **48.149 M4**	Grid 8 **55.197 M4**	Grid 9 **54.871 M4**

Cursor:
Total = 56.093 V/m
E Category: M4
Location: -5, 2.5, 8.7 mm



0 dB = 56.090V/m

Date/Time: 4/7/2011 2:13:25 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 836.52 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

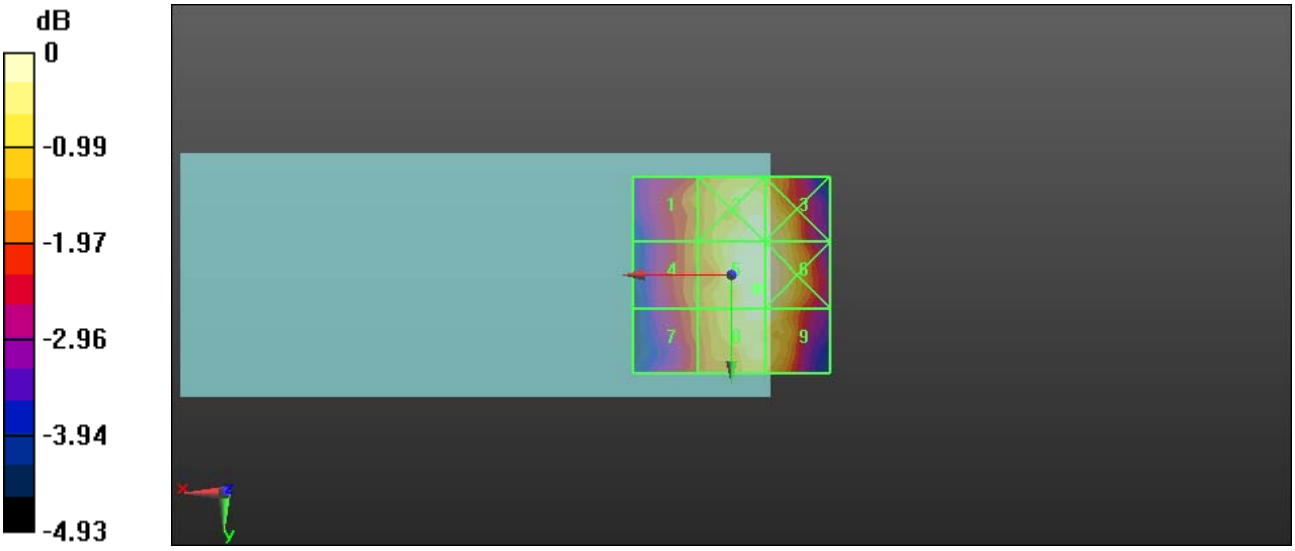
CDMA2000 Cell band_open/M ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 50.799 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 66.800 V/m; Power Drift = -0.43 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **43.016 M4**	Grid 2 **50.020 M4**	Grid 3 **49.902 M4**
Grid 4 **42.935 M4**	Grid 5 **50.799 M4**	Grid 6 **50.626 M4**
Grid 7 **42.212 M4**	Grid 8 **49.887 M4**	Grid 9 **49.807 M4**

Cursor:
Total = 50.799 V/m
E Category: M4
Location: -6.5, 3.5, 8.7 mm



0 dB = 50.800V/m

Date/Time: 4/7/2011 2:05:30 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 848.31 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

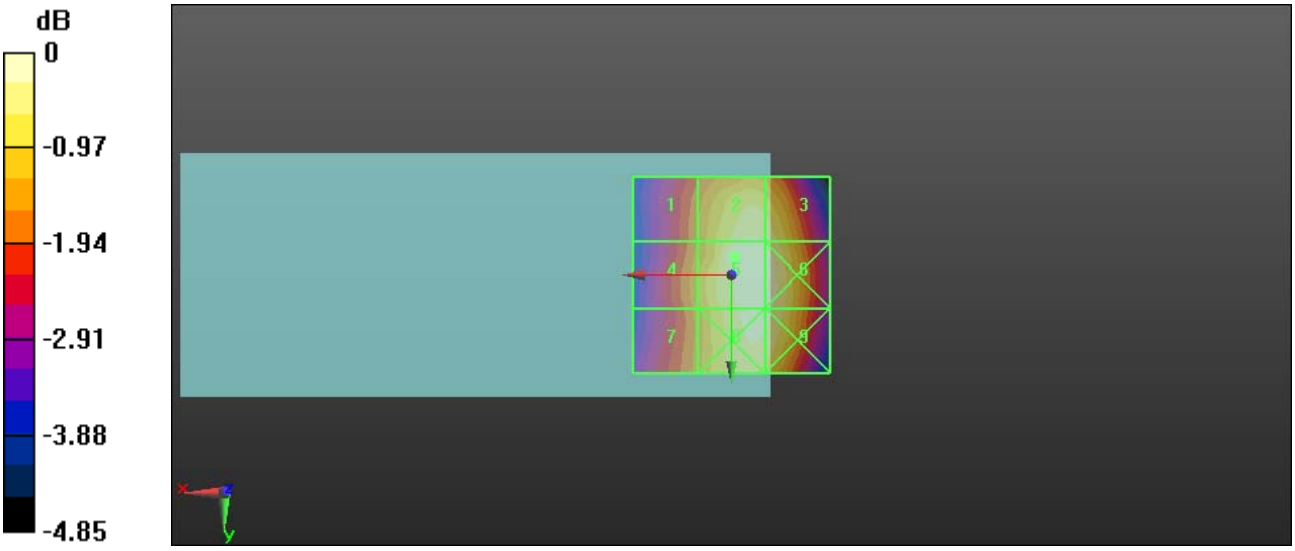
CDMA2000 Cell band_open/H ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 46.711 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 60.542 V/m; Power Drift = 0.08 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **38.935 M4**	Grid 2 **45.379 M4**	Grid 3 **44.886 M4**
Grid 4 **40.272 M4**	Grid 5 **46.711 M4**	Grid 6 **46.375 M4**
Grid 7 **39.772 M4**	Grid 8 **46.085 M4**	Grid 9 **45.815 M4**

Cursor:
Total = 46.711 V/m
E Category: M4
Location: -1, -4.5, 8.7 mm



0 dB = 46.710V/m

Date/Time: 4/7/2011 1:43:15 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 824.7 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

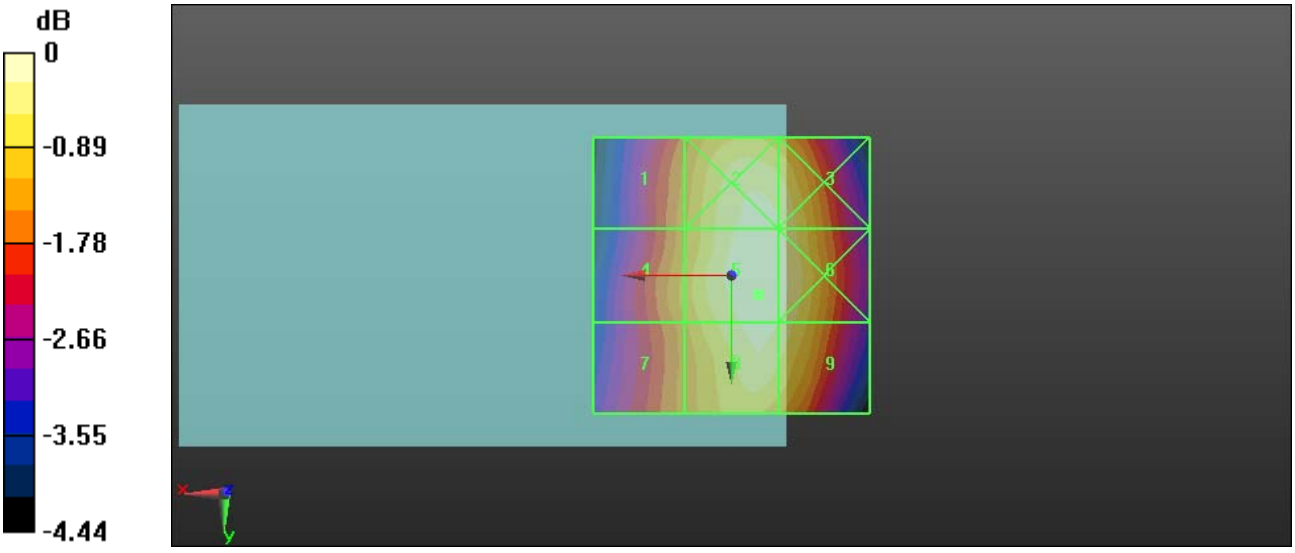
CDMA2000 Cell band_closed/L ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 56.993 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 75.057 V/m; Power Drift = -0.24 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **49.379 M4**	Grid 2 **55.934 M4**	Grid 3 **55.404 M4**
Grid 4 **50.520 M4**	Grid 5 **56.993 M4**	Grid 6 **56.031 M4**
Grid 7 **49.451 M4**	Grid 8 **55.991 M4**	Grid 9 **55.057 M4**

Cursor:
Total = 56.993 V/m
E Category: M4
Location: -5, 3.5, 8.7 mm



0 dB = 56.990V/m

Date/Time: 4/7/2011 1:36:40 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 836.52 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

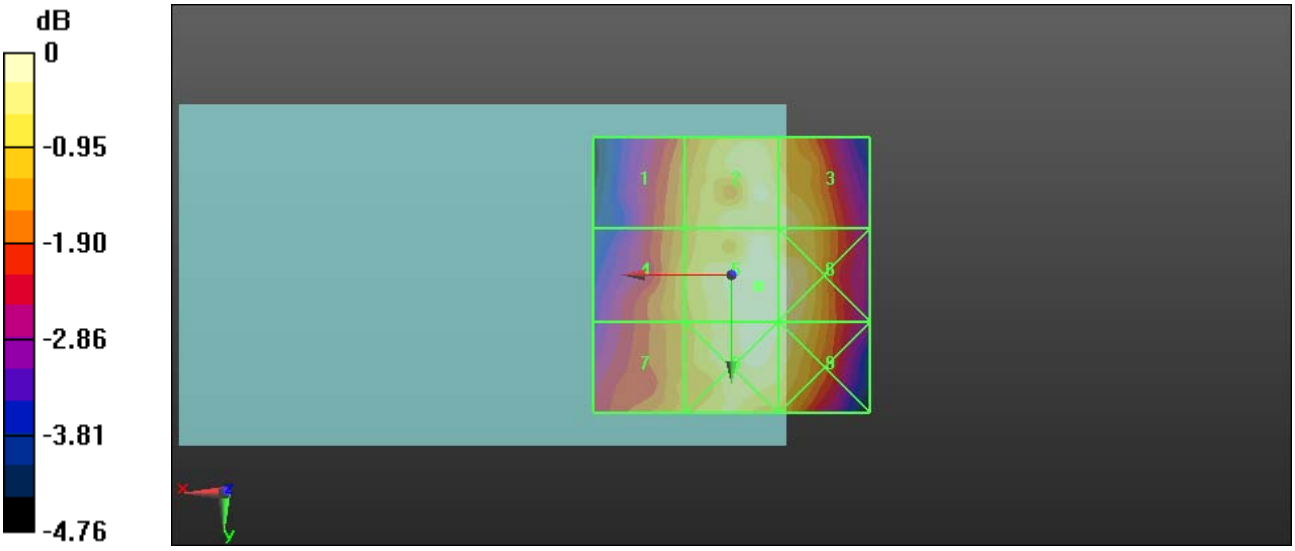
CDMA2000 Cell band_closed/M ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 52.747 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 68.745 V/m; Power Drift = -0.02 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **45.568 M4**	Grid 2 **51.586 M4**	Grid 3 **50.446 M4**
Grid 4 **47.074 M4**	Grid 5 **52.747 M4**	Grid 6 **52.286 M4**
Grid 7 **46.622 M4**	Grid 8 **51.684 M4**	Grid 9 **51.171 M4**

Cursor:
Total = 52.747 V/m
E Category: M4
Location: -5, 2, 8.7 mm



0 dB = 52.750V/m

Date/Time: 4/7/2011 1:53:52 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 848.31 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

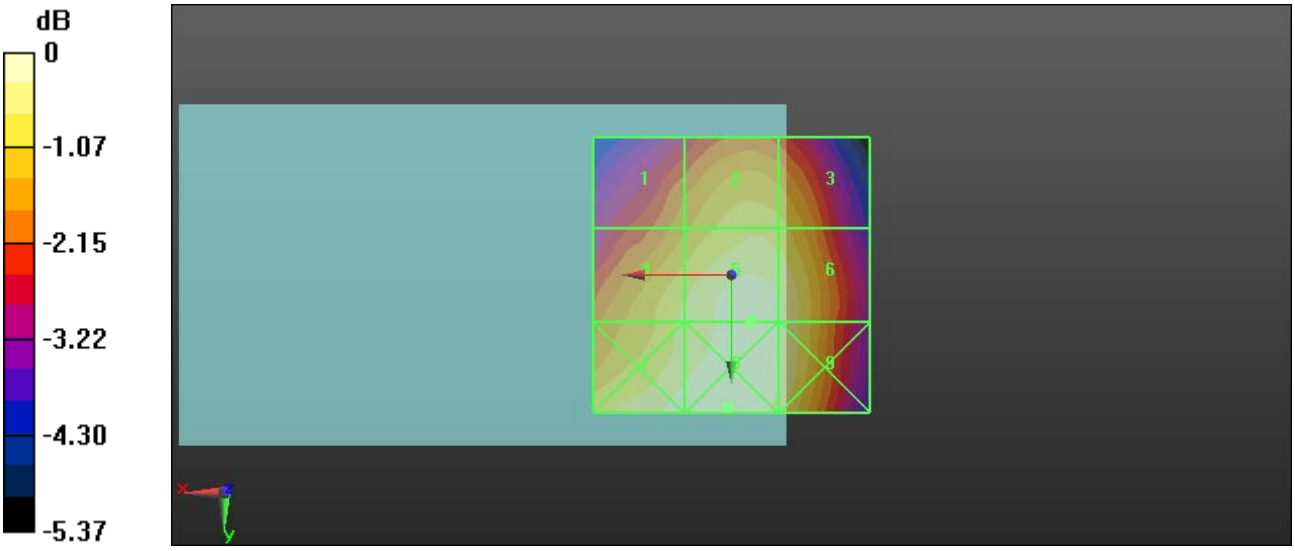
CDMA2000 Cell band_closed/H ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 49.818 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 66.155 V/m; Power Drift = -0.32 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **42.747 M4**	Grid 2 **46.436 M4**	Grid 3 **45.747 M4**
Grid 4 **47.251 M4**	Grid 5 **49.818 M4**	Grid 6 **49.057 M4**
Grid 7 **49.812 M4**	Grid 8 **50.803 M4**	Grid 9 **49.107 M4**

Cursor:
Total = 50.803 V/m
E Category: M4
Location: 0.5, 24, 8.7 mm



0 dB = 50.800V/m

Date/Time: 4/7/2011 2:49:31 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1851.25 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

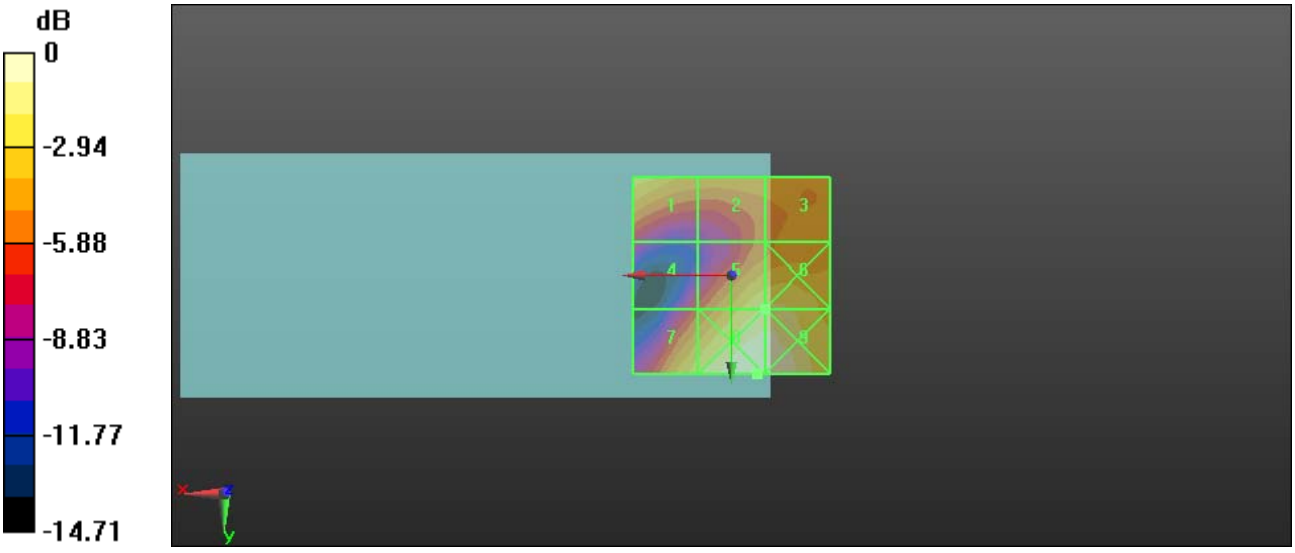
CDMA2000 PCS band_open/L ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 28.235 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 21.603 V/m; Power Drift = 0.01 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **26.605 M4**	Grid 2 **22.271 M4**	Grid 3 **21.927 M4**
Grid 4 **16.798 M4**	Grid 5 **28.235 M4**	Grid 6 **28.645 M4**
Grid 7 **27.102 M4**	Grid 8 **34.877 M4**	Grid 9 **34.725 M4**

Cursor:
Total = 34.877 V/m
E Category: M4
Location: -6.5, 25, 8.7 mm



0 dB = 34.880V/m

Date/Time: 4/7/2011 2:40:00 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1880 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

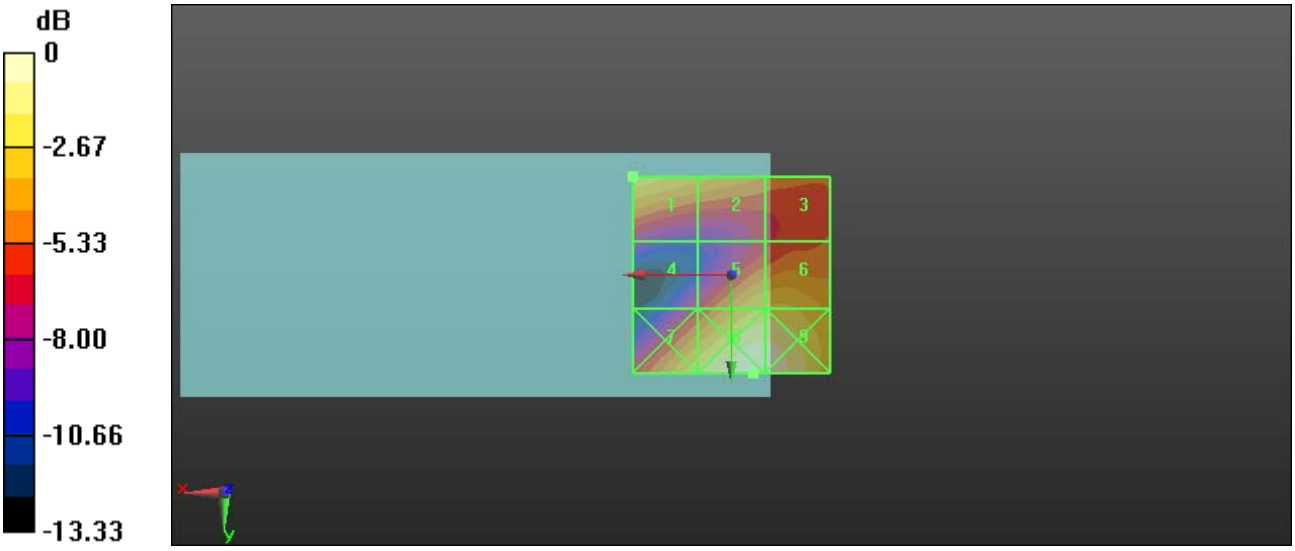
CDMA2000 PCS band_open/M ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 29.513 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 20.401 V/m; Power Drift = -0.36 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **29.513 M4**	Grid 2 **25.967 M4**	Grid 3 **22.102 M4**
Grid 4 **17.430 M4**	Grid 5 **27.871 M4**	Grid 6 **28.243 M4**
Grid 7 **30.010 M4**	Grid 8 **37.194 M4**	Grid 9 **36.706 M4**

Cursor:
Total = 37.194 V/m
E Category: M4
Location: -5.5, 25, 8.7 mm



0 dB = 37.190V/m

Date/Time: 4/7/2011 2:57:42 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1908.75 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

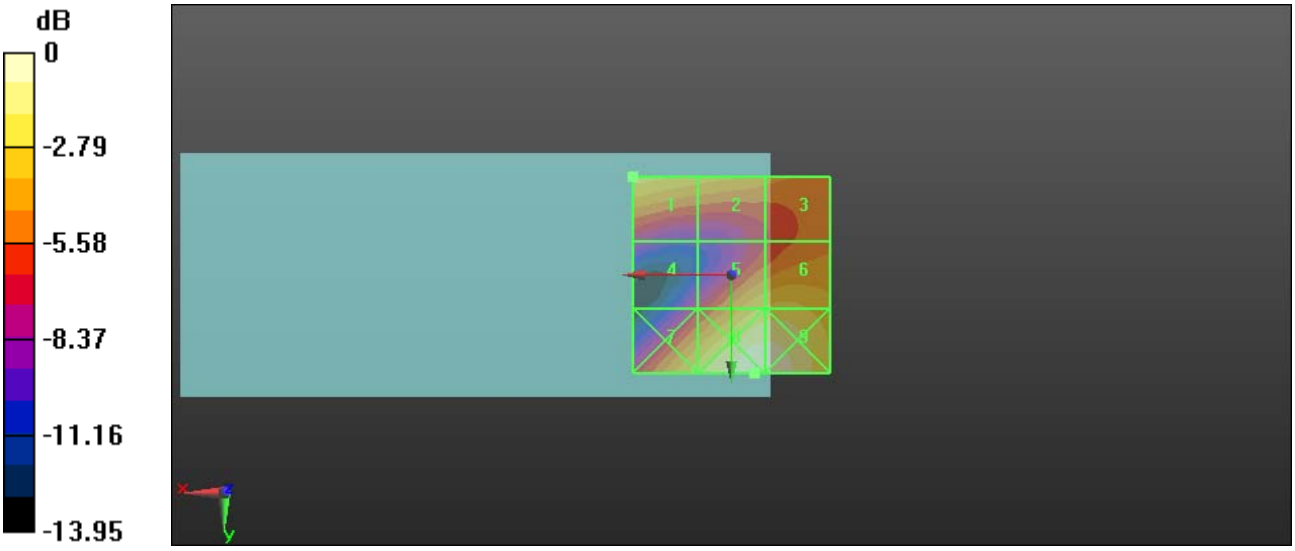
CDMA2000 PCS band_open/H ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 26.491 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 16.755 V/m; Power Drift = 0.07 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **26.491 M4**	Grid 2 **24.000 M4**	Grid 3 **21.459 M4**
Grid 4 **15.191 M4**	Grid 5 **25.588 M4**	Grid 6 **26.252 M4**
Grid 7 **27.059 M4**	Grid 8 **34.686 M4**	Grid 9 **34.162 M4**

Cursor:
Total = 34.686 V/m
E Category: M4
Location: -6, 25, 8.7 mm



0 dB = 34.690V/m

Date/Time: 4/7/2011 12:42:59 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1851.25 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

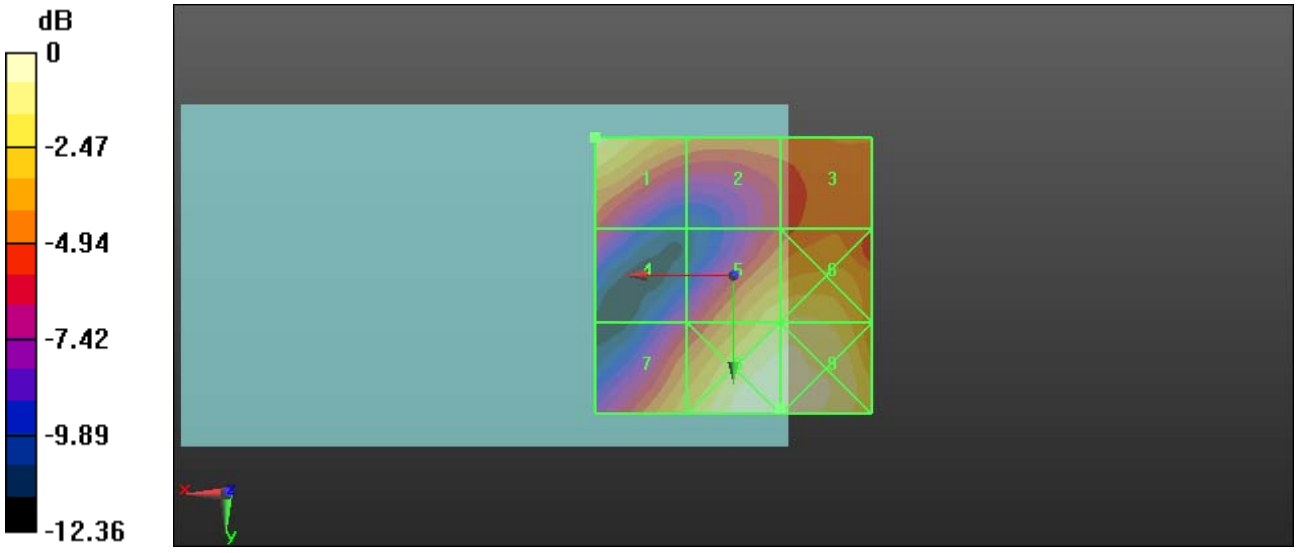
CDMA2000 PCS band_closed/L ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 28.496 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 20.682 V/m; Power Drift = -0.36 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **28.496 M4**	Grid 2 **21.164 M4**	Grid 3 **20.747 M4**
Grid 4 **17.098 M4**	Grid 5 **27.043 M4**	Grid 6 **27.780 M4**
Grid 7 **24.492 M4**	Grid 8 **32.805 M4**	Grid 9 **32.805 M4**

Cursor:
Total = 32.805 V/m
E Category: M4
Location: -8.5, 24, 8.7 mm



0 dB = 32.800V/m

Date/Time: 4/7/2011 12:32:25 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1880 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

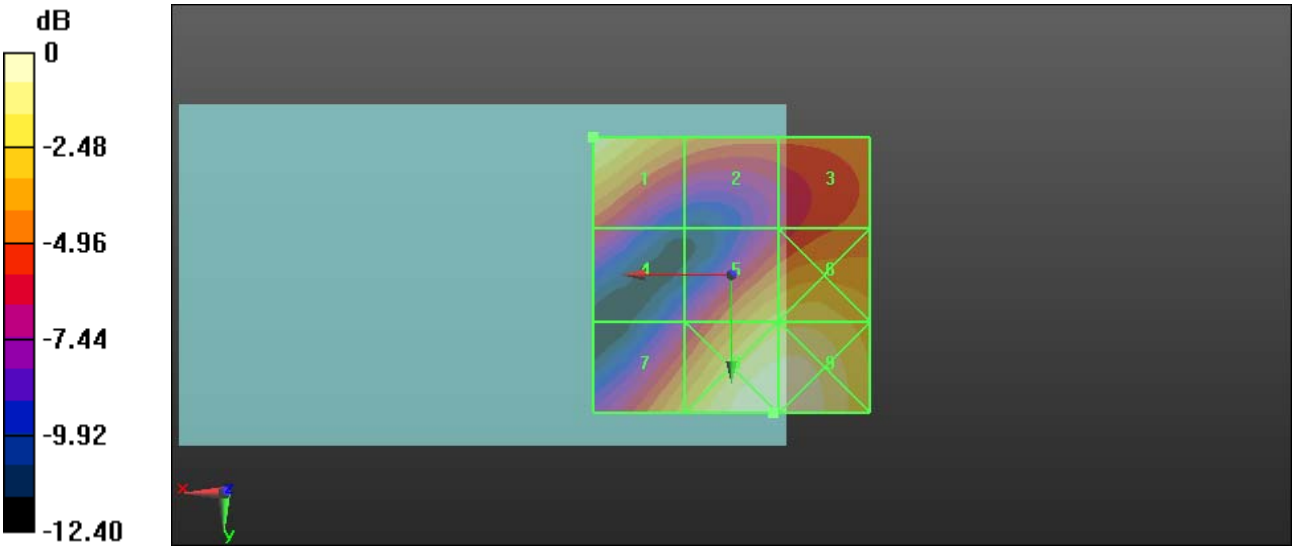
CDMA2000 PCS band_closed/M ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 31.404 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 17.937 V/m; Power Drift = 0.06 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **31.404 M4**	Grid 2 **22.647 M4**	Grid 3 **20.611 M4**
Grid 4 **18.313 M4**	Grid 5 **27.495 M4**	Grid 6 **28.387 M4**
Grid 7 **25.468 M4**	Grid 8 **34.960 M4**	Grid 9 **34.936 M4**

Cursor:
Total = 34.960 V/m
E Category: M4
Location: -7.5, 25, 8.7 mm



0 dB = 34.960V/m

Date/Time: 4/7/2011 1:19:39 PM

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1908.75 MHz;Duty Cycle: 1:1
Phantom section: TCoil Section
DASY4 Configuration:
- Probe: ER3DV6 - SN2339; ConvF(1, 1, 1); Calibrated: 1/20/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1);SEMCAD X Version 14.4.2 (2595)

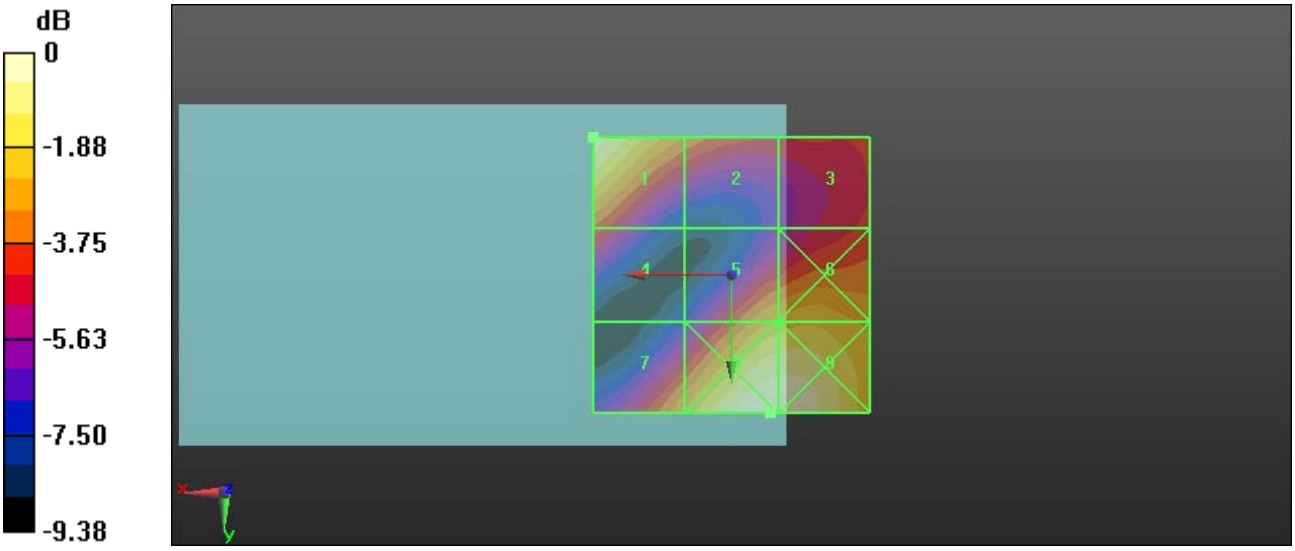
CDMA2000 PCS band_closed/H ch_E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 32.044 V/m
Probe Modulation Factor = 0.950
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 16.094 V/m; Power Drift = -0.36 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **32.044 M4**	Grid 2 **22.718 M4**	Grid 3 **20.265 M4**
Grid 4 **21.014 M4**	Grid 5 **24.988 M4**	Grid 6 **25.936 M4**
Grid 7 **24.717 M4**	Grid 8 **32.586 M4**	Grid 9 **32.518 M4**

Cursor:
Total = 32.586 V/m
E Category: M4
Location: -7, 25, 8.7 mm



0 dB = 32.590V/m